

General Description

The MDWC12D032ERH uses advanced Magnachip's MOSFET Technology, which provides high performance in on-state resistance and excellent reliability. Excellent low $R_{SS(ON)}$, low gate charge operation and operation for Battery Application.

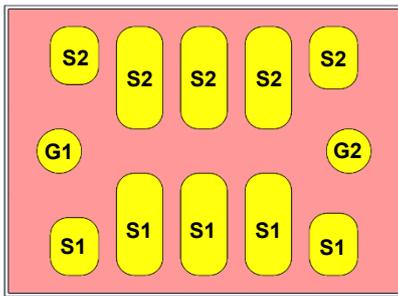
Features

- $V_{SS} = 12V$
- Source-Source ON Resistance;
 - $R_{SS(ON)} < 3.2m\Omega @ V_{GS} = 3.9V$
 - $R_{SS(ON)} < 4.5m\Omega @ V_{GS} = 3.1V$

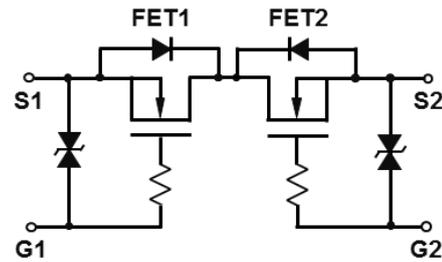
Applications

- Portable Battery Protection

Bottom View



2.23mm x 1.64mm WLCSP



Absolute Maximum Ratings

Characteristics		Symbol	Rating	Units
Source-Source Voltage		V_{SSS}	12	V
Gate-Source Voltage		V_{GSS}	±8	V
Source Current	DC ¹	I_S	15.3	A
	Pulse	I_{SP}	61.3	A
Total Power Dissipation	DC ¹	P_D	1.2	W
Channel Temperature		T_{ch}	-55~150	°C
Junction and Storage Temperature Range		T_J, T_{stg}	-55~150	°C

Thermal Characteristics

Characteristics	Symbol	Rating	Unit
Thermal Resistance	$R_{\theta JA}$	103.9	°C/W

Ordering Information

Part Number	Temp. Range	Package	Packing	RoHS Status
MDWC12D032ERH	-55~150 °C	WLCSP	Tape and Reel	Halogen Free

Electrical Characteristics (T_A =25°C unless otherwise noted)

Characteristics	Symbol	Test Condition	Min	Typ	Max	Units
Static Characteristics						
Source-Source Breakdown Voltage	BV _{SSS}	I _S = 250uA, V _{GS} = 0V	12	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{SS} = V _{GS} , I _S = 250uA	0.4	0.85	1.3	
Cut-Off Current	I _{SSS}	V _{SS} = 12V, V _{GS} = 0V	-	-	1.0	μA
Gate Leakage Current	I _{GSS1}	V _{GS} = ±8V, V _{SS} = 0V	-	-	10	μA
	I _{GSS2}	V _{GS} = ±5V, V _{SS} = 0V	-	-	1	
Source-Source Resistance	R _{SS(ON)}	V _{GS} = 3.9V, I _S = 5.0A	-	2.55	3.20	mΩ
		V _{GS} = 3.1V, I _S = 5.0A	-	3.20	4.50	
Dynamic Characteristics						
Total Gate Charge	Q _g	V _{DD} = 6V, I _S = 5.0A, V _{GS} = 3.9V	-	25.6	-	nC
Gate-Source Charge	Q _{gs}		-	4.00	-	
Gate-Drain Charge	Q _{gd}		-	9.43	-	
Input Capacitance	C _{iSS}	V _{SS} = 6V, V _{GS} = 0V, f = 50kHz	-	3149	-	pF
Reverse Transfer Capacitance	C _{rSS}		-	917	-	
Output Capacitance	C _{oss}		-	1097	-	
Turn-On Delay Time	t _{d(on)}	V _{GS} = 3.9V, V _{DD} = 6V, I _S = 5.0A, R _{GEN} = 3Ω	-	0.03	-	μS
Rise Time	t _r		-	0.22	-	
Turn-Off Delay Time	t _{d(off)}		-	2.98	-	
Fall Time	t _f		-	8.87	-	
Drain-Source Body Diode Characteristics						
Source-Source Diode Forward Voltage	V _{F(S-S)}	I _F = 5A, V _{GS} = 0V	-	0.75	1.2	V

Note *1. Mounted on PCB Board (14.9mm x 25.0mm x t1.6mm)

Characteristic Graph

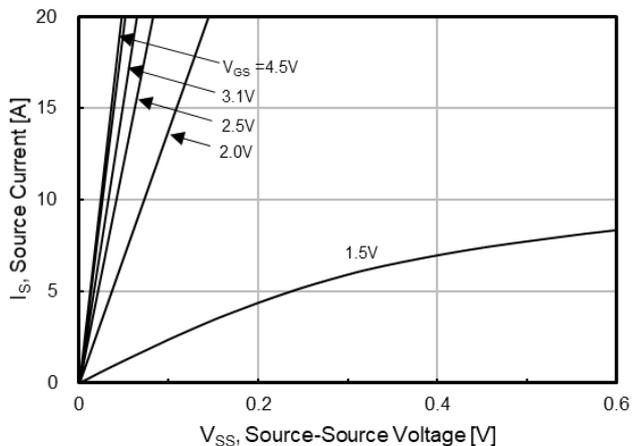


Fig.1 On-Region Characteristics

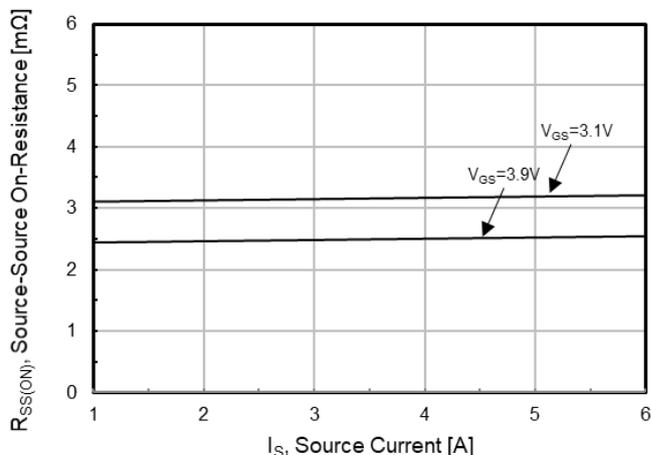


Fig.2 On-Resistance Variation with Drain Current and Gate Voltage

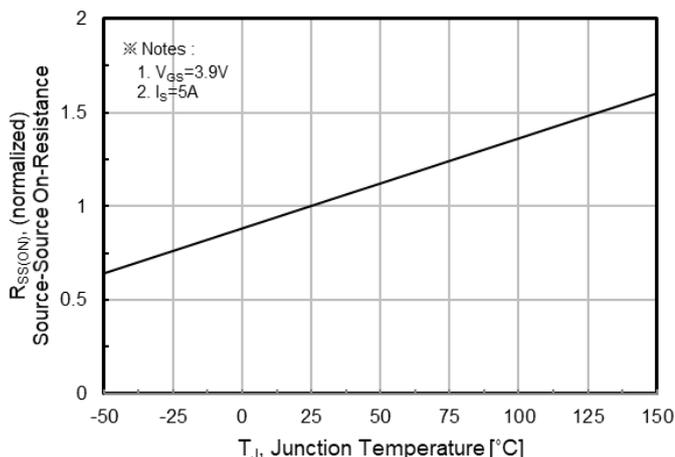


Fig.3 On-Resistance Variation with Temperature

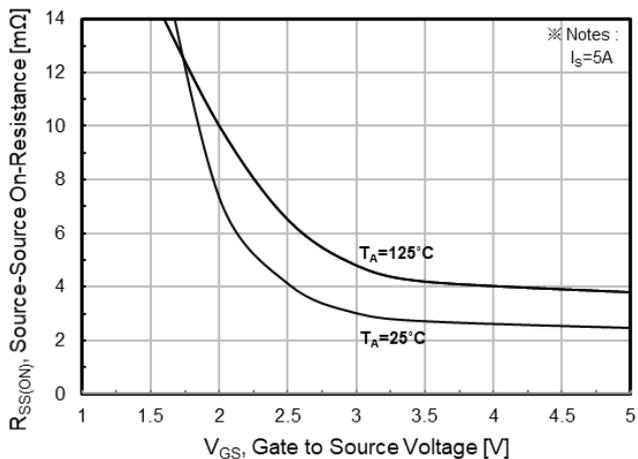


Fig.4 On-Resistance Variation with Gate to Source Voltage

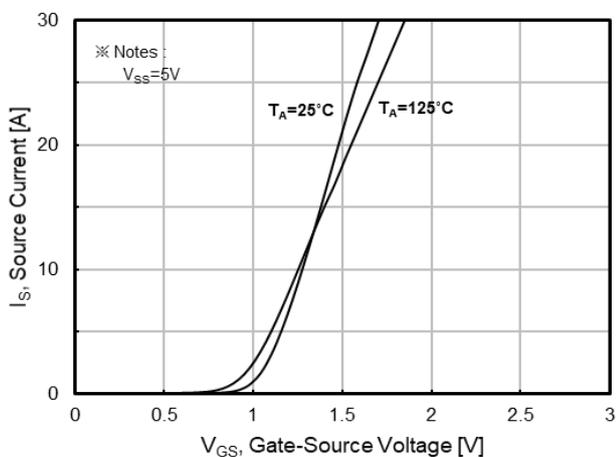


Fig.5 Transfer Characteristics

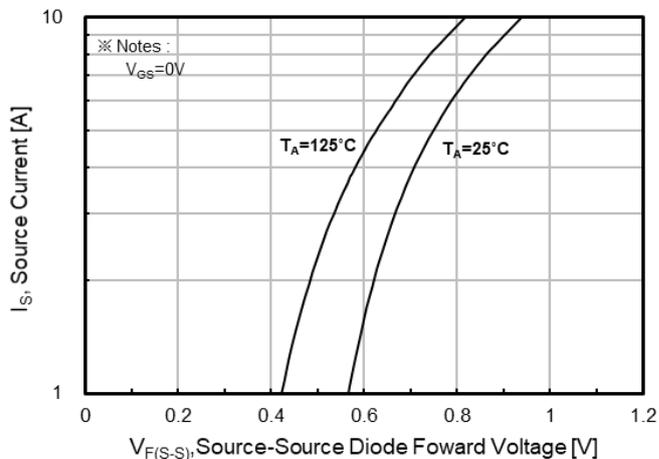


Fig.6 Forward Source to Source Characteristics

Characteristic Graph

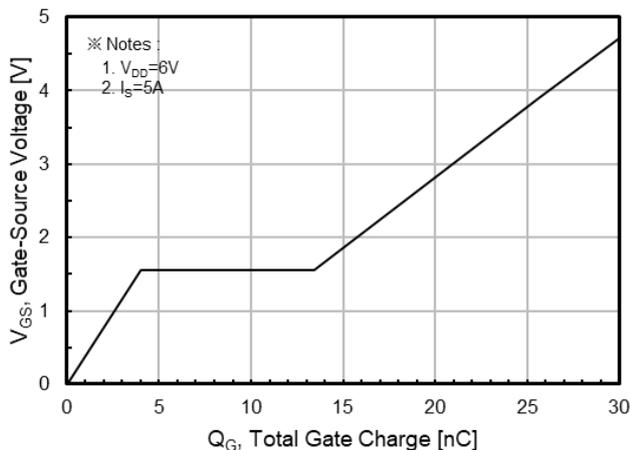


Fig.7 Gate Charge Characteristics

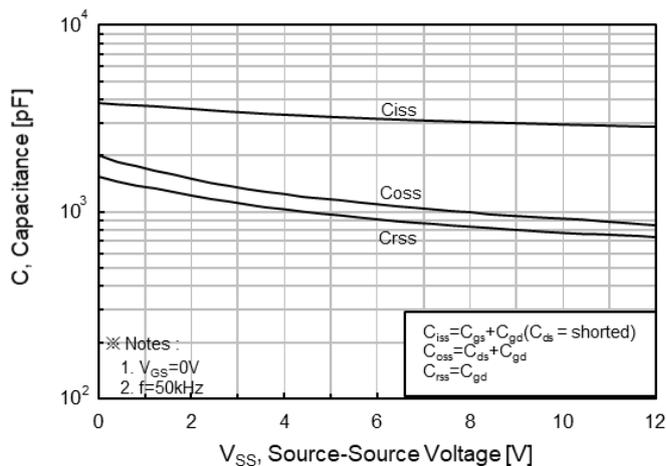


Fig.8 Capacitance Characteristics

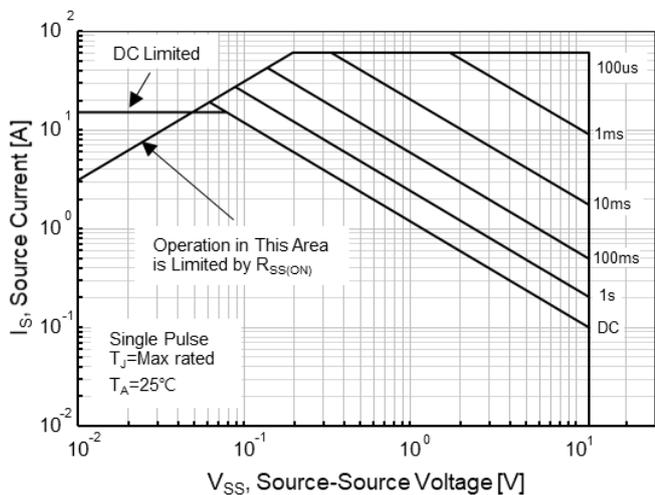


Fig.9 Maximum Safe Operating Area

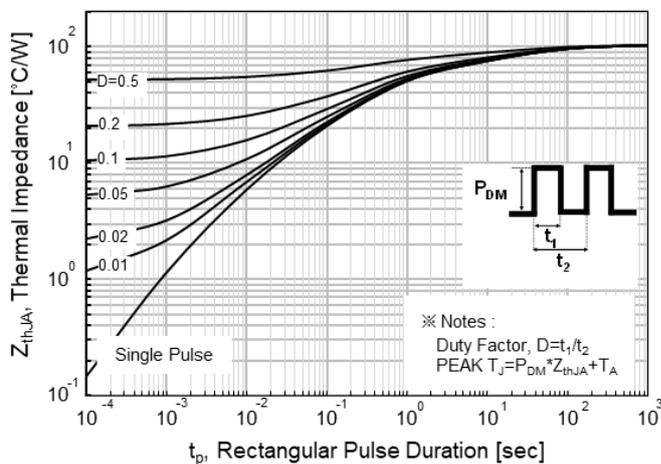
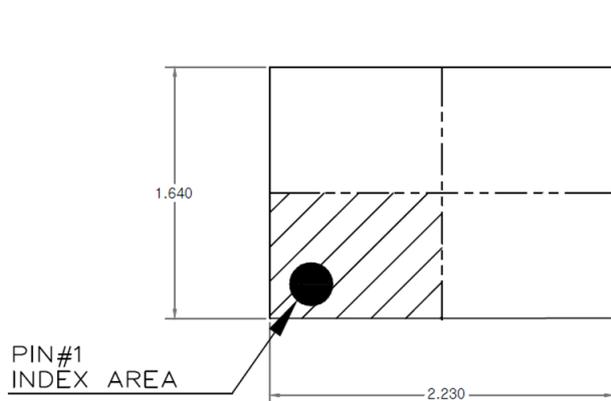
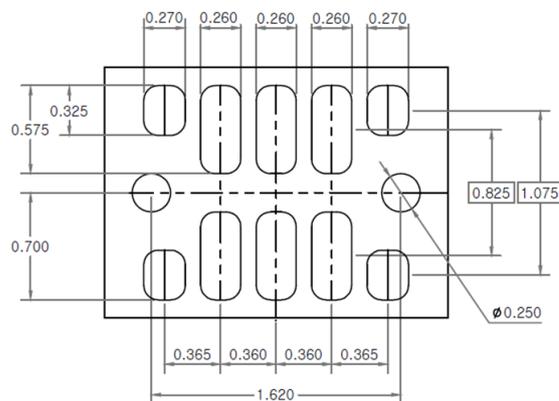


Fig.10 Transient Thermal Response Curve

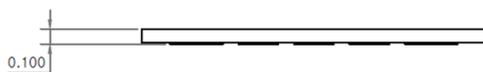
PACKAGE OUTLINE



TOP VIEW (Mark Side)



BOTTOM VIEW



SIDE VIEW

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. GENERAL TOLERANCE : $\pm 0.03\text{mm}$
3. PACKAGE BODY SIZES EXCLUDE FLASH & BURRS

DISCLAIMER:

The Products are not designed for use in hostile environments, including, without limitation, aircraft, nuclear power generation, medical appliances, and devices or systems in which malfunction of any Product can reasonably be expected to result in a personal injury. Seller's customers using or selling Seller's products for use in such applications do so at their own risk and agree to fully defend and indemnify Seller.

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